

From crafting to visualization: low-dimensional TMD nanostructures under the electron microscope lamppost

Sonia Conesa-Boj

Department of Quantum Nanoscience, Kavli Institute of Nanoscience, Delft University of Technology, 2600 GA Delft, The Netherlands

One of the driving forces of the ongoing nanotechnology revolution is the ever-improving ability to understand and control the properties of quantum matter down to the atomic scale. Key drivers in this revolution are quantum materials, such as the two-dimensional (2D) materials of the transition metal dichalcogenide (TMD) family. The realization of novel TMD-based devices relies heavily on understanding the relation between structural and electrical properties at the nanoscale. The ultimate goal is that of crafting TMD nanostructures in a way that makes possible the tailored control of their properties. In this talk, recent studies illustrating novel fabrication approaches of TMD nanostructures based on combining top-down and bottom-up methods will be presented. These allow to control the resulting geometries and material combinations, making possible the realization of novel functionalities such as metallic edge states arising in MoS₂ nanowalls and nanotubes, enhanced nonlinear response in vertically-oriented MoS₂ nanostructures, and surface and edge plasmons in WS₂ nanoflowers. I will emphasize the crucial role that cutting-edge transmission electron microscopy techniques play in these studies, together with that of machine learning techniques which make possible extract a wealth of novel information which would be lost otherwise.

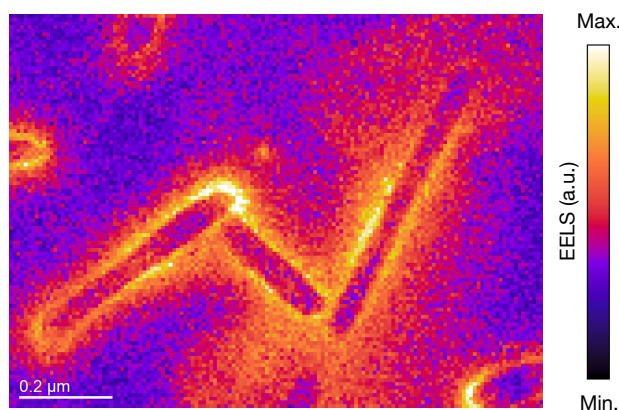


Figure 1. Experimental study of low-loss EELS acquired in MoS₂ nanotubes. Intensity map of the EELS signals integrated for a energy-loss window between 1-2 eV.